MILLIMETER WAVE (MMW) TRANSCEIVER MODULE WITH TRANSMITTER, RECEIVER AND LOCAL OSCILLATOR FREQUENCY MULTIPLIER SURFACE MOUNTED CHIP SET

Related Application

This application is based upon prior filed copending provisional application Serial No. 60/292,389 filed May 21, 2001.

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Field of the Invention

This invention relates to microwave monolithic integrated circuit (MMIC) radio frequency modules, and more particularly, this invention relates to a millimeter wave (MMW) transceiver module using microwave monolithic integrated circuit (MMIC) chip packages.

Background of the Invention

15 Microwave monolithic integrated circuits
(MMIC) used in radio frequency (RF) modules have
traditionally been built in low to medium volume. The
key elements that prevented this technology from
attaining high volume production, similar to surface
20 mount technology components, is the difficulty in
working with fragile MMIC chips and the tight
tolerances required when manufacturing such components.

A millimeter wave (MMW) module is typically made up of dozens of MMIC chips, substrates and

25 discrete components mounted with epoxy or solder to a Coefficient of Thermal Expansion (CTE) matched carrier

or similar machined housing. The radio frequency components are typically connected to other components and terminal pads via wire or ribbon bonds. Tuning of the radio frequency modules after assembly is almost always required.

Although many chip manufacturers are now offering individual MMIC chips in a surface mount package, an entire receiver, transmitter or local oscillator (LO) multiplier have not been provided in a single chip package to enable production of a MMW module with fewer surface mounted components. In addition, the unavailability of a wide array of surface mount MMIC chips has caused designers to shy away from their use because of the requirement to mix bare die with surface mount chips.

Another reason why single transmitter, receiver or LO multiplier MMIC chip packages have not been available is because these types of devices require some level of filtering of unwanted signals. A receiver requires image rejection, a transmitter requires local oscillator (LO) signal rejection, and a frequency multiplier requires filtering of a fundamental frequency. Prior art filters used in conjunction with such devices were traditionally made from thin film material, and were too large to mount into a small chip package. Some prior art devices, however, have been fabricated as a MMW receiver chip using image reject mixers, such as shown in FIG. 1.

FIG. 1 illustrates a receiver chip 20, having a low noise amplifier 22 that receives the radio frequency signal, a capacitor 24 connected to ground, and DC signal coming in and operative at drain voltage V_d. An image reject mixer 26 receives the local oscillator (LO) signal and is operative with in-phase (I) and quadrature (Q) channels. An external L-band

hybrid combiner 28 receives the intermediate frequency, as illustrated. These receiver chips have not seen wide commercial acceptance because of their limited image reject performances and the requirement to use an external I/Q hybrid combiner 28 to obtain a single IF output. A hybrid combiner at L-band also is very large in comparison to the high frequency chips used in such devices.

10 Summary of the Invention

The present invention advantageously overcomes the prior art drawbacks and provides a millimeter wave (MMW) transceiver module and method of fabricating same by using a low cost microwave

15 monolithic integrated circuit (MMIC) transceiver chip set that is surface mounted on a circuit board, such as a printed circuit board of the type known to those skilled in the art. The MMIC chips are provided as miniature sized surface mount packages and use

20 multilayer, low temperature, co-fired ceramic thick film technology, such as formed from layers of low temperature transfer tape using fabrication techniques known to those skilled in the art.

In accordance with one aspect of the present
invention, the millimeter wave (MMW) transceiver module
of the present invention includes a circuit board and a
microwave monolithic integrated circuit (MMIC)
transceiver chip set that is surface mounted on the
circuit board. The MMIC transceiver chip set includes
a receiver MMIC chip package, a transmitter MMIC chip
package, and a local oscillator (LO) multiplier MMIC
chip package. Each chip package is surface mounted on
the circuit board. These components are operatively
connected to each other through appropriate connections
via the circuit board for millimeter wave transceiver

operation. Each MMIC chip package includes a base and a multilayer substrate board formed from layers of low temperature transfer tape and received on the base. The multilayer substrate board has at least three layers and carries RF signals, DC signals, grounding and embedded passive components, including resistors and capacitors. MMIC chips are received on the multilayer substrate.

In one aspect of the present invention, a

filter is formed on the multilayer substrate board and operatively connected to the at least one MMIC chip. The filter is formed by vertically stacked resonators in the multilayer substrate board. In one aspect of the present invention, the filter includes a plurality of coupled line millimeter wavelength resonators formed as stripline or microstrip and positioned on a filter surface defined on the multilayer substrate board. The filter includes radio frequency contacts and conductive vias extending through the multilayer substrate board.

The filter could also include a plurality of isolation vias extending through the multilayer substrate board.

In yet another aspect of the present invention, the base can be formed as an alumina plate that is metal plated. Heat sink vias could be formed within the base. The multilayer substrate board also includes a substrate on which the low temperature transfer tape layers are mounted. Each layer of low temperature transfer tape could be about three mil thick, but the range in dimensions could be higher or lower as designed and fabricated by one skilled in the art. A top layer of the multilayer substrate board has chip cut-outs for receiving MMIC chips therein. A plurality of interconnects and interconnect vias are positioned within the low temperature transfer tape layers forming the substrate board.

In another aspect of the present invention, the receiver MMIC chip package includes a low noise amplifier, a mixer and an image rejection filter. The transmitter MMIC chip package includes a power

5 amplifier, mixer and a local oscillator signal filter. The local oscillator multiplier MMIC chip package

A method is also disclosed for forming the 10 millimeter wave (MMW) transceiver module of the present invention.

filtering a fundamental frequency.

includes an x-band mixer, amplifier and a filter for

Brief Description of the Drawings

Other objects, features and advantages of the
15 present invention will become apparent from the
detailed description of the invention which follows,
when considered in light of the accompanying drawings
in which:

FIG. 1 is a block diagram of a prior art
20 receiver with image reject mixer and an external L-band hybrid combiner.

FIG. 2A is a block diagram of a receiver circuit architecture that can be implemented in a single composite microwave monolithic integrated circuit chip package and showing in block format a transmitter MMIC chip package and local oscillator multiplier chip package surface mounted on a circuit board.

FIG. 2B is a plan view of the layout of the 30 multilayer substrate board for the receiver MMIC chip package of the present invention.

FIG. 3 is a plan view of a base formed as an alumina plate that is metal plated, in accordance with one aspect of the present invention.

FIG. 4A is a plan view of an interconnect layer as one of the layers used in the multilayer substrate board, in accordance with one aspect of the present invention.

FIG. 4B is a plan view of an example of a top layer of the multilayer substrate board that can be used in the present invention.

FIG. 5A is a block diagram of a transmitter circuit that could be used for the transmitter MMIC chip package of the present invention.

FIG. 5B is a plan view of the layout of a transmitter MMIC chip package multilayer substrate board.

FIG. 6 is a block diagram of a local

15 oscillator multiplier circuit architecture that can be used for the local oscillator (LO) multiplier MMIC chip package of the present invention.

FIG. 6B is a plan view of a multilayer substrate board that can be used for the local oscillator (LO) multiplier MMIC chip package.

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multilayer, thick film, millimeter wave radio frequency transceiver module as an example of fabrication techniques that could be applied to the present invention and showing a cover, channelization section, multilayer thick film section and a lower plate.

FIG. 8 is an exploded isometric view of various layers of a thick film section showing an example of fabrication techniques that could be applied to the present invention.

FIG. 9 is an exploded isometric view of a transceiver module and showing various connections as an example of fabrication techniques that could be applied to the present invention.

FIGS. 10-15 are examples of filters formed in low temperature co-fired ceramic layer material such as low temperature transfer tape and shown as examples of fabrication techniques that can be applied to the present invention.

Detailed Description of the Preferred Embodiments

The present invention will now be described more fully hereinafter with reference to the accompanying drawings, in which preferred embodiments 10 of the invention are shown. This invention may, however, be embodied in many different forms and should not be construed as limited to the embodiments set forth herein. Rather, these embodiments are provided 15 so that this disclosure will be thorough and complete, and will fully convey the scope of the invention to those skilled in the art. Like numbers refer to like elements throughout.

The present invention is advantageous and 20 uses advances in multilayer, low temperature, co-fired ceramic, thick film technology to provide an advanced design and efficient fabrication of a microwave monolithic integrated circuit (MMIC) transceiver module by providing a low cost MMIC transceiver chip set, 25 including receiver, transmitter and local oscillator multiplier chip packages that measure only about 0.2 by 0.25 inches, in one aspect of the present invention, as a non-limiting example. As to the semiconductor devices, it should be understood that commercial offthe-shelf (COTS) devices can be used to fabricate the module and chip packages of the present invention.

FIG. 2A is a block diagram of a receiver circuit architecture and shows a receiver circuit that can be implemented in a low cost receiver MMIC chip 35 package of the present invention as indicated by the

dashed lines at 30. The receiver MMIC chip package 30 is surface mounted on a printed circuit board 32, as an example, together with a transmitter MMIC chip package 34 and local oscillator (LO) multiplier chip package 36.

As illustrated in FIG. 2A, a low noise amplifier 38 receives a radio frequency signal and a DC signal with drain voltage V_d that is capacitor 40 connected to ground. A bandpass filter 42 is operative 10 with a mixer 44 that receives a local oscillator signal and intermediate frequency using circuit techniques and fundamentals known to those skilled in the art. present invention provides a multilayer, low temperature, co-fired ceramic film substrate board 46, 15 as shown in FIG. 2B, that implements the receiver circuit architecture in a single composite chip. As illustrated, the low noise amplifier 38 and mixer MMIC chips 38,44 are operatively connected to an image reject filter 42 that can be formed by fabrication 20 techniques as described in commonly assigned U.S. patent application serial no. 09/933,128, filed August 20, 201, and titled "Millimeter Wave Filter For Surface Mount Applications, " the disclosure which is hereby incorporated by reference in its entirety.

As illustrated, the low noise amplifier 38, filter 42 and mixer 44 are operatively connected using pads 50 formed on the substrate 46. The filter includes isolation vias 52 dispersed around the formed filter 42. Other connection points as terminals 54 are for DC signals, radio frequency signals, intermediate frequency signals, and local oscillator signals. Other formed components, such as a cap 56, are illustrated. The different layers include interconnects, traces, embedded passive components and other circuit

components and connections as described below and as suggested by those skilled in the art.

that receives the multilayer thick film, low

temperature, co-fired ceramic film layers forming the
multilayer substrate board 46, and a cover (not shown),
such as made out of a 10-15 mil alumina, in one aspect
of the present invention. The base plate 58 can be
formed from alumina or other materials suggested by
those skilled in the art, and is plated with a metal,
such as gold, as indicated by the darker colored areas
58a. The metallized surface 58a can be for soldering,
grounding, and other uses.

The multilayer substrate board 46 is 15 preferably fabricated using low temperature transfer tape (LTTT) technology and closely follows the steps used in well established multilayer thick film processing, including multiple dielectric printing per layer, as replaced by a tape lamination step. Although low temperature transfer tape technology is not the 20 only type of fabrication technology that can be used with the present invention, it is preferred. Both gold and silver conductor systems can be used with low temperature transfer tape technology and can be applied 25 to a wide variety of dielectric materials and substrates, although a material that has been selected as an example for this application is a standard 96% alumina substrate. As illustrated, terminals 60 are formed for DC signals, an intermediate frequency (IF) 30 signal, and a radio frequency (RF) signal. Heat sink vias 62 are formed within the base plate 58 by techniques known to those skilled in the art.

The multilayer substrate board 46 can include at least three layers, such as formed from low

temperature transfer tape as described. These layers can carry RF signals, DC signals, grounding, and embedded passive components, including resistors and capacitors. Further details of fabrication techniques of a multilayer substrate board that could be used as modified for the present invention are disclosed in commonly assigned U.S. patent application serial no. 09/863,030, filed May 22, 2001, and titled "Thick Film Millimeter Wave Transceiver Module," the disclosure which is hereby incorporated by reference in its entirety.

Special formulated conductive material can be screen printed on a substrate, such as an alumina substrate, using standard thick film equipment and processing techniques developed for forming conductive interconnects and interlayer vias. Tape sheets can be bonded to a substrate using the combination of heat and pressure, as known to those skilled in the art.

FIGS. 4A and 4B illustrate examples of the 20 types of layers that could be used for the present invention. FIG. 4A illustrates an interconnect layer 64 having interconnect vias 64a and interconnect lines 64b as formed by techniques known to those skilled in the art. The total number of layers can vary, and in one application as described, could be three tape 25 layers, with a substrate and ground plane layer additionally added when necessary. Each layer could be about three mil thick. This type of multilayer low temperature transfer tape alumina substrate is 30 particularly attractive for use with Galium Arsenide (GaAs) chips because of the CTE (coefficient of thermal expansion) of about 7.1. This material can also be used with heat transfer vias and has excellent thermal conduction. The MMIC GaAs chips can be attached

directly to a substrate using gold tin solder preforms or silver epoxy.

As shown in FIG. 4B, the top one or two layers 66 would have cut-outs that are made

5 substantially exactly to the size of any MMIC chips to be used in the MMIC chip package. As shown in FIG. 4B, a first chip cut-out 66a would receive a low noise amplifier MMIC chip of the receiver circuit and a second chip cut-out 66b would receive a mixer MMIC

10 chip. The top layers could mount a portion of the formed image reject filter used in a receiver. Other local oscillator, DC, RF and IF terminals and pads 66c could be formed as required.

implementation in a single transmitter MMIC chip package 34 and the associated circuit (FIG. 5A), which includes a mixer 68 that receives an intermediate frequency and local oscillator signal. A bandpass filter 69 is operable with a power amplifier 70, which receives DC signals and radio frequency signals in a circuit architecture of the type known to those skilled in the art. The circuit includes the appropriate capacitors 71 and ground connections and the gate and drain voltages (V_g and V_d). The filter 69 is operative as a local oscillator signal reject filter.

FIG. 5B illustrates a plan view of the multilayer substrate board 72 for the transmitter that could be formed from low temperature co-fired ceramic materials using low temperature transfer tape. This view shows a power amplifier 70 connected by pads 73 to the local oscillator reject filter 69 and mixer 68.

Isolation vias 74 are also formed around the local oscillator reject filter 69. Terminals 75 are included as in the multilayer substrate board shown in FIG. 2B.

FIGS. 6A and 6B illustrate a local oscillator multiplier implementation in a single composite MMIC chip package 36. The circuit that can be used as part of the chip package 36 is shown in FIG. 6A and includes 5 an x-band mixer 76 that receives a DC signal associated with the gate voltage V_q. Capacitors 77 are connected to ground. A feedback loop circuit 78 is operative with the amplifier 79, which is interconnected to the bandpass filter 80 for rejecting a fundamental 10 frequency. X-band and KA-band signals are operative with the local oscillator multiplier circuit as illustrated. The amplifier receives gate voltage V_q and the feedback loop circuit 78 is operative with drain voltage V_d. FIG. 6B illustrates an exemplary plan view 15 of the multilayer substrate board 82 with the amplifier 79, filter circuit 80 and X3 band mixer 76, including the isolation vias 83, terminals 84, and various pads 85 of the type as described before.

Naturally, the type of circuits and choice of embedded components, signal traces, circuit lines, such as microstrip lines, and the vias formed in the substrate can vary in design, fabrication, and implementation depending on the design and fabrication techniques chosen by one skilled in the art.

A MMIC chip package, whether receiver, transmitter or local oscillator multiplier, can be formed in accordance with the present invention using various techniques known to those skilled in the art. In one non-limiting example, the alumina base plate, cover, multilayer thick film having the embedded passives and filters, and MMIC chips can be delivered in waffle packs or similar packaging. These packages are placed on an automatic Pick and Place (P&P) machine that could be programmed to dispense silver epoxy, pick

the MMIC chips, and place them in respective cut-outs on the top man and place with the presence of the man and the top and a second to the top and the top the epoxy.

The assembly is heated to a temperature to errect curring of every composite chip.

The is estimated accomplished for every composite chip. that the total pick and place per chip package would effect curing of the silver epoxy. take about ten seconds and the number of chips that could be packaged in a day using a single pick and After the epoxy is cured, the chips are wire place machine could be well over 8,000. After Wire bonding, ponded for us and kr connections. After wire pondito the chip package assembly a cover is attached on top of the chip package assembly a cover is attached. a cover 18 accarded on cop of the entire composite chip

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The entire composite chip

a cover 18 accarded to 10W remnerature ouring avoid to bonded for DC and RF connections. is subjected to low temperature curing cycle to cure the non-conductive epoxy. ready to be used as surface mount parts. ror purposes of fabrication techniques for representative examples of fabrication. 10 substrates; and filters that are formed in multilayer MMIC CHIP transceivers, multilayer thick film Substrates are illustrated in FIGS. 7-15 to give substrates are types of manufacturing and fabrication examples of the types are types of manufacturing and fabrication of manufacturing and fabrication of manufacturing and fabrication of the types of types of the types of types of the types of types examples of the types of manufacturing and labertoatic methods and devices that could be modified by those methods and devices that could be modified by those mernoas and devices that could be modified by those invention.

skilled in second art for use with the present invention. transceiver module using thick film technology transcelver module using temperature co-fired ceramic tape low temperature co-fired ceramic including green tape technology. Cecimioropy. Substrate board 150 having different layers multilayer of low temperature transfer tape including a DC signals layer including a DC signal signa embedded capacitors and resistors layer 156, solder FIG. 7 illustrates how the different layers in FIG. 8 can be combined to form a multilayer thick preform layer 158, and top layer 160.

film substrate board 150 that is received on a base plate 162. A channelization plate 164 is illustrated as an example (if used) and a radio frequency cover 166. Isolation vias 167 are shown and illustrated.

5 These vias can extend across multiple layers to a ground layer. They can be formed by techniques known to those skilled in the art.

FIG. 9 shows a MMIC transceiver module 170 having a waveguide interface 172 built into a

10 channelization plate 164 and showing intermediate frequency outputs 174, a local oscillator input 176, an intermediate frequency input 178, various DC pins 180, module connectors 182, and external connectors 184 positioned on a CCA.

15 The MMIC module assembly process is improved by using the low cost multilayer transfer tape thick film board 150 for attaching MMIC chips 186 and embedding all the peripherals and electrical connections in the multilayer thick film.

20 MMIC module production is made similar to surface mount technology by packaging the MMIC modules to allow complete automation of the assembly process.

As shown in FIG. 7, this module, as an example, is made up of a base plate 162, multilayer alumina substrate

25 150 formed from the layers, a channelization plate 164 and a cover 166.

The base plate 162 can be a gold plated flat sheet of low cost CTE matched material, such as Cooper Tungsten (CuW), about 1/8 inch thick, in one aspect of the invention. The plate is only cut to size and requires no machining.

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The multilayer substrate board 150 is fabricated using the Low Temperature Transfer Tape (LTTT) technology (similar to green tape technology),

as well known to those skilled in the art, similar to low temperature co-fired ceramic (LTCC) sheets. The LTTT processing closely follows the steps used in well established multilayer thick film processing, as known to those skilled in the art. The multiple dielectric printing per layer is replaced by a tape lamination step. Both gold and silver conductor systems can be used with LTTT. Interconnects and vias are formed by techniques known to those skilled in the art.

Multilayer structures can be applied to a wide variety of dielectric materials and substrate, the material selected for this aspect of the present invention can be a standard 96% alumina substrate, as a non-limiting example. Any special formulated conductor materials are screen printed on the alumina substrate, using standard thick film equipment and processing techniques developed for forming conductive interconnects and interlayer vias. The tape sheets are bonded to the substrate using a combination of heat and pressure with a range established by those skilled in the art.

that can be used to form an alumina board. The number of layers can be as high as 12, or more, although in the previously described embodiment above, three layers were considered. The layers could be formed on a base substrate (S), as illustrated, of the type known to those skilled in the art. Each layer could be about 2 to about 4 mil thick, and typically about 3 mil thick, and can be used to carry low frequency RF signals, DC signals, ground, or embedded passive components, such as capacitors and resistors as described before. Interconnect or ground vias could be implemented across one or more layers of LTTT film.

This multilayer LTTT alumina substrate is

particularly attractive for use with GaAs chip because
of its beneficial CTE coefficient (about 7.1). Also,
this material has excellent thermal conduction (25-200)

5 W/MK). Any MMIC GaAs chips could be attached directly
to the substrate using gold tin solder pre-forms or
silver epoxy. In cases of thermal concerns, the chips
could be attached directly to the base plate using CTE
matched shims, or on top of thermal vias that are

10 connected to the bottom surface. These vias can be
formed by techniques known to those skilled in the art.
For ease of assembly and wire bonding, the top layer (3
to 4 mil thick) can have cut-outs made exactly to the
size of the chips (see FIG. 9) as described relative to

The multilayer substrate costs on the average about \$1.5 to \$2.5 per layer per square inch. Up to 275 vias per square inch are possible.

The channelization plate 164, if used, could

20 be formed of gold plated aluminum, although other
materials could be used. The channels 164a can be cut
using wire EDM methods. Any channels 164a can be
created to provide the isolation required between the
transmitter and receiver signals and generate a cut off
to the lower frequency signals. The RF cover could
also be made of gold plated aluminum.

FIG. 9 illustrates a transceiver module including a surface mount circuit card assembly (CCA) used to provide a regulator/controller function. SMA connectors could be attached directly to the multilayer substrate. An RF interface waveguide is provided as part of the channelization plate.

The module shown in FIG. 9 can be assembled by the following technique as one non-limiting example.

- 1. Pick and place all the MMIC chips on to the multilayer alumina substrate. The substrate should have all the low frequency signals connections, DC connections, ground connections, passive devices already embedded in the layers and the solder pre-form.
 - 2. Pick and place the DC connector and any low frequency SMA connectors used for IF and LO signals.
- 3. Flow the solder in a vacuum oven to attached the MMIC die and the connectors to the substrate board. Silver epoxy may be used in place of the solder.
 - 4. Wire/wedge bond the MMIC chips to the substrate board.
- 5. Attach the substrate board to the base plate and the channelization plate using epoxy.
 - 6. Install RF cover.
 - 7. Install the regulator/controller surface mount CCA.
- illustrated a filter structure as parallel coupled line filters produced using thick film, low temperature co-fired ceramic materials. The following description is given as an example of fabrication techniques that could be modified and applied to the filter construction used in MMIC chip packages 30, 34 and 36 as described above. Further details are found in commonly assigned and copending U.S. patent application serial no. 09/933,269, filed August 20, 2001, entitled "Millimeter Wave Filter For Surface Mount Application," the disclosure which is hereby incorporated by reference in its entirety.

FIG. 10 shows an exemplary filter formed as a two-pole filter 220 with individual hairpin resonators 222. The filter is made using an alumina carrier plate

224 that is about 25 mil thick and acts as a dielectric
base plate having opposing surfaces. A ground plane
layer 226 is formed on a surface of the dielectric base
plate 224. A low temperature co-fired ceramic layer

5 228 is positioned over the ground plane layer 226 and
defines an outer filter surface 230. This low
temperature co-fired ceramic layer 228 is formed of a
layer of low temperature co-fired ceramic 228, formed
as Low Temperature Transfer Tape (LTTT), i.e., green

10 tape. It is formed about 5 to about 7 mils thick with
a ground plane layer separating the dielectric base
plate and the green tape layer.

A plurality of coupled line millimeter
wavelength hairpin resonators 222 are formed as either

15 stripline or microstrip and positioned on the outer
filter surface 230. Radio frequency terminal contacts
232 are positioned on the surface of the dielectric
base plate opposite the low temperature co-fired
ceramic layer 228 formed from the green tape. As

20 illustrated, conductive vias 234 extend through the low
temperature co-fired ceramic layer 228, ground plane
layer 226, and dielectric base plate, i.e., carrier
plate 224, and each interconnect the radio frequency
terminal contacts 232 and the end positioned coupled

25 line resonators 222a formed on the outer filter surface
230.

The dielectric base plate is formed about 10 to about 35 mils thick (and preferably in one aspect about 25 mils thick) and formed from alumina, also 30 known as aluminum oxide, a well known ceramic dielectric material. Other dielectric materials could be used as suggested by those skilled in the art.

As shown in FIG. 12, a lower ground plane layer 235 is positioned on the surface of the

dielectric base plate 224 opposite the upper positioned ground plane layer 226 and the green tape layer 228 and isolated from the radio frequency terminal contacts as illustrated by the two parallel formed lines. A 5 plurality of isolation vias 236 extend through the low temperature co-fired ceramic (green tape) layer 228 and dielectric base plate 224 and substantially engage the parallel strips forming lower ground plane layer 235. As shown in FIG. 10, the isolation vias 236 isolate the formed filter.

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A dielectric or other cover 238 can be positioned over the outer filter surface 230 (and cover an entire substrate surface forming part of the MMIC chip package). This cover 238 could have a metallized interior surface 240, such as formed from gold layer or similar material and could be spaced from the hairpin resonators 222 for generating a predetermined cut-off frequency. This cover 238 also shields the formed filter from outside interference. The distance between 20 the microstrip and the top of the cover could be about 20 mils, but can vary depending on what is required by one skilled in the art. If the filter is made of stripline only, a cover 238 may not be required.

FIGS. 13-15 illustrate a plurality of green tape layers 250 that are formed as low temperature 25 co-fired ceramic layers and positioned over a first ground plane layer. Intervening ground plane layers 252 are positioned between green tape layers 250. This plurality of low temperature co-fired ceramic layers 30 250 that are formed as green tape and the interposed ground plane layers 252 form a low temperature co-fired ceramic multilayer substrate board. A plurality of millimeter wavelength stripline hairpin resonators 254 are formed on the ceramic layers 250 between the outer

filter 230 surface and the dielectric base (carrier)
plate 224 and isolated by the interposed ground plane
layers 252. As illustrated, conductive vias 257
interconnect the hairpin resonators 256 formed on the
ceramic layers and outer filter surface. This
configuration illustrates a multilayer, six-pole filter
258, which is created by cascading three two-pole
filters in three different layers, with one microstrip
filter 262 and two stripline filters 264, as
illustrated.

These filters can have a nominal size of about 150 mil by about 100 mil and can be fabricated on large, six inch single layer or multilayer wafers and cut to size with an appropriate laser. The alumina cover 238 having the metallized interior surface can be attached to the filter using conductive silver epoxy. Where the top filter resonators are made of stripline only, a cover will not be required.

Many modifications and other embodiments of
the invention will come to the mind of one skilled in
the art having the benefit of the teachings presented
in the foregoing descriptions and the associated
drawings. Therefore, it is to be understood that the
invention is not to be limited to the specific
embodiments disclosed, and that the modifications and
embodiments are intended to be included within the
scope of the dependent claims.